

## SILICON CONTROLLED RECTIFIERS 0.8 AMP, 30 THRU 200 VOLT



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The CENTRAL SEMICONDUCTOR 2N5060 series devices are epoxy molded SCRs designed for control systems and sensing circuit applications.

## MARKING: FULL PART NUMBER

**MAXIMUM RATINGS:** (T<sub>A</sub>=25°C unless otherwise noted)

**TO-92 CASE** 

|  | SYMBOL                              | 2N5060 | 2N5061 | 2N5062    | 2N5063 | 2N5064 | UNITS            |
|--|-------------------------------------|--------|--------|-----------|--------|--------|------------------|
| Peak Repetitive Off-State Voltage                        | V <sub>DRM</sub> , V <sub>RRM</sub> | 30     | 60     | 100       | 150    | 200    | V                |
| RMS On-State Current (Note 1; T <sub>C</sub> =80°C)      | I <sub>T(RMS)</sub>                 |        |        | 0.8       |        |        | А                |
| Average On-State Current (Note 1; T <sub>C</sub> =67°C)  | IT(AV)                              |        |        | 0.51      |        |        | А                |
| Average On-State Current (Note 1; T <sub>C</sub> =102°C) | ) I <sub>T(AV)</sub>                |        |        | 0.255     |        |        | А                |
| Peak One Cycle Surge Current (60Hz)                      | ITSM                                |        |        | 10        |        |        | А                |
| I <sup>2</sup> t Value for Fusing (t=8.3ms)              | l <sup>2</sup> t                    |        |        | 0.4       |        |        | A <sup>2</sup> s |
| Peak Forward Gate Power (tp≤1.0µs)                       | PGM                                 |        |        | 0.1       |        |        | W                |
| Average Forward Gate Power (t=8.3ms)                     | P <sub>G(AV)</sub>                  |        |        | 0.01      |        |        | W                |
| Peak Forward Gate Current (tp<1.0µs)                     | IGM                                 |        |        | 1.0       |        |        | А                |
| Peak Reverse Gate Voltage (tp≤1.0µs)                     | V <sub>RGM</sub>                    |        |        | 5.0       |        |        | V                |
| Operating Junction Temperature                           | Тј                                  |        | -      | 40 to +12 | 5      |        | °C               |
| Storage Temperature                                      | T <sub>sta</sub>                    |        | -      | 40 to +15 | 0      |        | °C               |
| Thermal Resistance (Note 2)                              | ΘJC                                 |        |        | 75        |        |        | °C/W             |
| Thermal Resistance                                       | $\Theta_{JA}$                       |        |        | 200       |        |        | °C/W             |
| Notes: 1) 180° Conduction Angles                         |                                     |        |        |           |        |        |                  |

s: 1) 180° Conduction Angles
2) Measured with the "flat side down" on a heatsink and held in position by a metal clamp over the curved surface.

| ELECTRICAL                          | CHARACTERISTICS: (T <sub>C</sub> =25°C unless otherwise n                              | oted) |     |     |       |
|-------------------------------------|--|-------|-----|-----|-------|
| SYMBOL                              | TEST CONDITIONS  | MIN   | TYP | MAX | UNITS |
| I <sub>DRM</sub> , I <sub>RRM</sub> | V <sub>D</sub> =Rated V <sub>DRM</sub> , R <sub>GK</sub> =1.0kΩ                        |       |     | 10  | μA    |
| I <sub>DRM</sub> , I <sub>RRM</sub> | V <sub>D</sub> =Rated V <sub>DRM</sub> , R <sub>GK</sub> =1.0kΩ, T <sub>C</sub> =110°C |       |     | 50  | μA    |
| lgt                                 | V <sub>D</sub> =7.0V, R <sub>L</sub> =100Ω   |       |     | 200 | μA    |
| lgt                                 | V <sub>D</sub> =7.0V, R <sub>L</sub> =100Ω, T <sub>C</sub> =-40°C                      |       |     | 350 | μA    |
| IН                                  | Initiating Current, I <sub>T</sub> =20mA, R <sub>GK</sub> =1.0k $\Omega$               |       |     | 5.0 | mA    |
| Ч                                   | Initiating Current, IT=20mA, R_{GK}=1.0k\Omega, T_C=-40°C                              |       |     | 10  | mA    |
| V <sub>GT</sub>                     | V <sub>D</sub> =7.0V, R <sub>L</sub> =100Ω   |       |     | 0.8 | V     |
| V <sub>GT</sub>                     | V <sub>D</sub> =7.0V, R <sub>L</sub> =100Ω, T <sub>C</sub> =-40°C                      |       |     | 1.2 | V     |
| V <sub>GD</sub>                     | V <sub>D</sub> =Rated V <sub>DRM</sub> , R <sub>L</sub> =100Ω, T <sub>C</sub> =110°C   | 0.1   |     |     | V     |
| V <sub>TM</sub>                     | I <sub>TM</sub> =1.2A, T <sub>A</sub> =25°C  |       |     | 1.7 | V     |
| dv/dt                               | V <sub>D</sub> =Rated V <sub>DRM</sub> , R <sub>GK</sub> =1.0kΩ                        |       | 30  |     | V/µs  |

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### 2N5060 THRU 2N5064

## SILICON CONTROLLED RECTIFIERS 0.8 AMP, 30 THRU 200 VOLT

# ELECTRICAL CHARACTERISTICS - Continued: (T<sub>C</sub>=25°C unless otherwise noted) 2N5062

| SYMBOL         | TEST CONDITIONS   | 2N5060<br><u>2N5061</u><br>TYP | 2N5063<br><u>2N5064</u><br>TYP | UNITS |
|----------------|---|--------------------------------|--------------------------------|-------|
| t <sub>d</sub> | V <sub>D</sub> =Rated V <sub>DRM</sub> , I <sub>GT</sub> =1.0mA,  | 3.0                            | 3.0                            | μs    |
| t <sub>r</sub> | Forward Current=1.0A, di/dt=6.0A/µs   | 0.2                            | 0.2                            | μs    |
| tq             | Forward Current=1.0A, tp=50µs,<br>0.1% Duty Cycle, di/dt=6.0A/µs,<br>dv/dt=20V/µs, I <sub>GT</sub> =1.0mA | 10                             | 30                             | μs    |

R1



## **TO-92 CASE - MECHANICAL OUTLINE**

| DIMENSIONS |       |       |             |      |  |  |
|------------|-------|-------|-------------|------|--|--|
|            | INC   | HES   | MILLIMETERS |      |  |  |
| SYMBOL     | MIN   | MAX   | MIN         | MAX  |  |  |
| A (DIA)    | 0.175 | 0.205 | 4.45        | 5.21 |  |  |
| В          | 0.170 | 0.210 | 4.32        | 5.33 |  |  |
| С          | 0.500 | -     | 12.70       | -    |  |  |
| D          | 0.016 | 0.022 | 0.41        | 0.56 |  |  |
| E          | 0.100 |       | 2.54        |      |  |  |
| F          | 0.050 |       | 1.27        |      |  |  |
| G          | 0.125 | 0.165 | 3.18        | 4.19 |  |  |
| Н          | 0.080 | 0.105 | 2.03        | 2.67 |  |  |
|            | 0.015 |       | 0.38        |      |  |  |

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## LEAD CODE:

Cathode
Gate
Anode

MARKING: FULL PART NUMBER

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### SERVICES

- · Bonded Inventory
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- Custom Electrical Characteristic Curves
- SPICE Models
- Custom Packaging
- Package Base Options
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